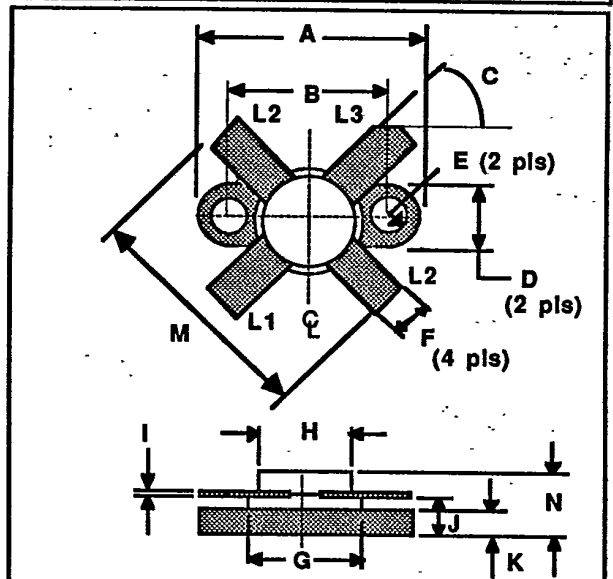


GENERAL DESCRIPTION

The S15-28 is designed for driver and output applications in the HF, 1.6-30 MHz range. It features state-of-the-art ruggedness and linearity and may be operated Class A, AB or C.

S15-28
15 WATTS - 28 VOLTS
1.5 - 30 MHZ

HF COMMUNICATIONS



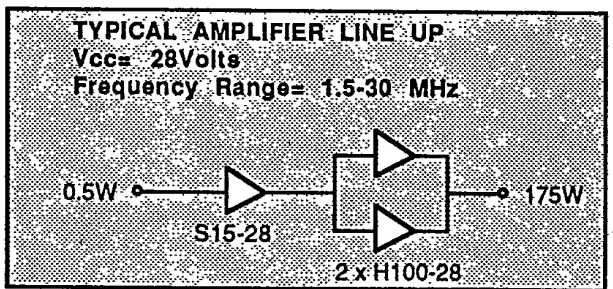
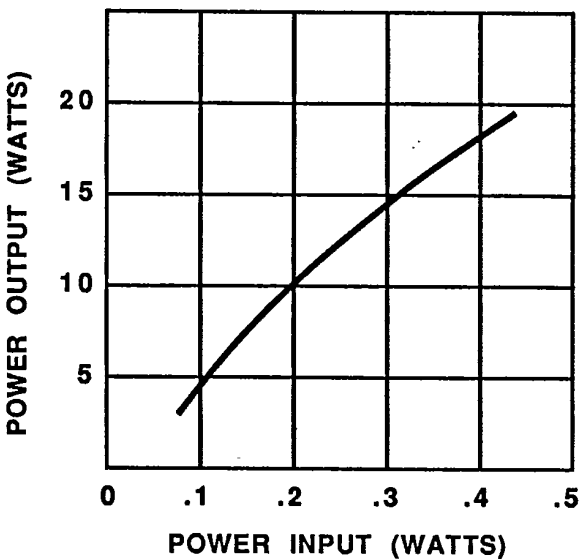
ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C Case Temperature	35 W
Maximum Voltage and Current	
BVces Collector to Emitter Voltage	60 V
BVebo Emitter to Base Voltage	4.0 V
Ic Collector Current	2.0 A

Maximum Temperatures	
Storage Temperature	-65 to +150 °C
Operating Junction Temperature	+200 °C

DIM	Millimeter	TOL	Inches	TOL	
L1 : B	A	24.76	.13	.975	.005
L2 : E	B	18.41	.13	.725	.005
L3 : C	C	45°	5°	45°	5°
	D	6.35	.13	.250	.005
	E	3.17	.13	.125	.005
	F	5.69	.13	.224	.005
	G	9.52	.13	.375	.005
	H	8.63	.13	.340	.005
	I	0.13	.02	.005	.001
	J	4.32	.13	.170	.005
	K	2.54	.13	.100	.005
	M	25.55	.25	1.006	.010
	N	6.68	REF	.263	REF

POWER OUTPUT VS POWER INPUT (TYPICAL)

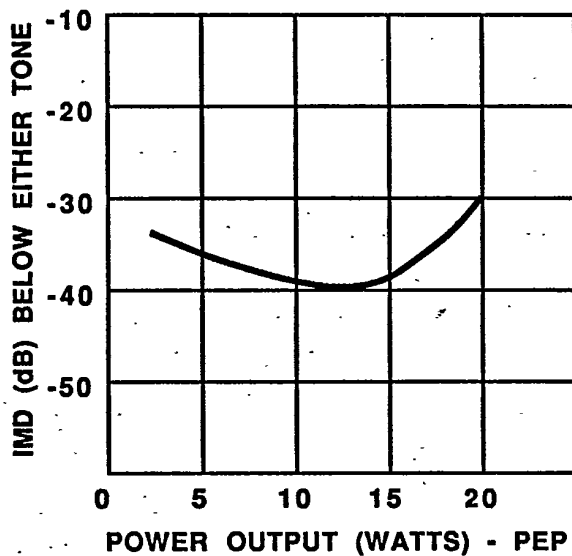
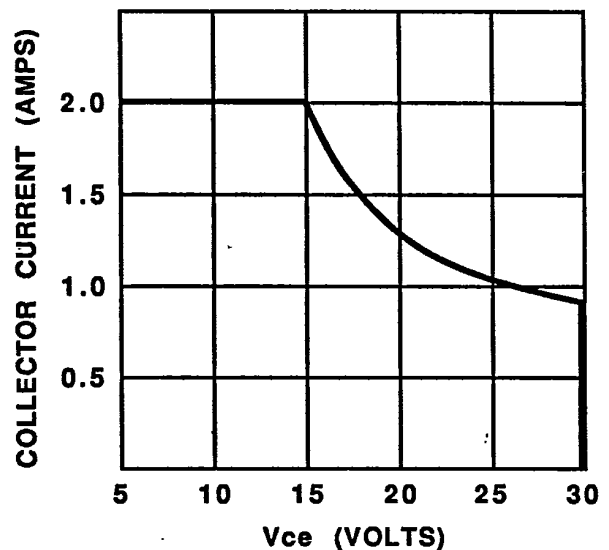


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S15-28-2

ELECTRICAL CHARACTERISTICS¹

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
P _{out}	Power Output	f= 30MHZ V _{cc} = 28V	15			Watts
P _{in}	Power Input				0.5	Watts
P _g	Power Gain		15			dB
η_c	Collector Efficiency			60		%
VSWR	Load Mismatch Tolerance				$\infty:1$	
BV _{ebo}	Breakdown Voltage (Emitter to Base)	I _c = 0A, I _e = 5mA	4.0			Volts
BV _{ces}	Breakdown Voltage (Collector to Emitter)	V _{be} = 0A, I _c = 15mA	60			Volts
BV _{ceo}	Breakdown Voltage (Collector to Emitter)	I _b = 0A, I _c = 50mA	33			Volts
IMD	Intermodulation Distortion	15W (PEP), f= 30 MHz		-38	-35	dBc
C _{ob}	Capacitance-Collector to Base	V _{cb} = 28V, f= 1 MHz		20		pF
h_{FE}	DC-Current Gain	V _{ce} = 5V, I _c = 1A	10		100	
θ_{jc}	Thermal Resistance				5	°C/W

Note 1: T_c = +25°C unless otherwise specifiedIMD VS POWER OUTPUT
(TYPICAL)DC SAFE OPERATING AREA
(TYPICAL)

SPECIFICATIONS MAY BE SUBJECT TO CHANGE WITHOUT NOTICE

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